# Reliability Report SN54SC245-SEP Production Flow and Reliability Report



#### ABSTRACT

This report presents the reliability and qualification results for the SN54SC245-SEP radiation-tolerant, 1.2-V to 5.5-V, octal bus transceivers. The SN54SC245-SEP is manufactured with a controlled baseline and has the following:

- An extended product life cycle
- One assembly and test site
- Product traceability
- Extended product-change notification

### Table of Contents

1 Texas Instruments Enhanced Product Qualification and Reliability Report	2
2 Space Enhanced Plastic Production Flow	
2.1 Device Introduction	
2.2 SN54SC245-SEP Production Flow Chart	. 4
3 Device Qualification	. 5
3.1 Qualification by Similarity (Qualification Family)	
4 Outgas Test Report	

### **List of Figures**

Figure 2-1. Space Enhanced Plastic Production Flow
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### **List of Tables**

Table 3-1. Space Enhanced Products New Device Qualification Matrix	5
Table 4-1. Outgas Test Results	<mark>6</mark>

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1



## 1 Texas Instruments Enhanced Product Qualification and Reliability Report

TI qualification testing is a risk mitigation process that is engineered to assure device longevity in customer applications. Wafer fabrication process and package level reliability are evaluated in a variety of ways that may include accelerated environmental test conditions with subsequent derating to actual use conditions. Manufacturability of the device is evaluated to verify a robust assembly flow and assure continuity of supply to customers, TI Enhanced Products are qualified with industry standard test methodologies performed to the intent of Joint Electron Devices Engineering Council (JEDEC) standards and procedures. Texas Instruments Enhanced Products are certified to meet GEIA-STD-0002-1 *Aerospace Qualified Electronic Components*.



# **2 Space Enhanced Plastic Production Flow**

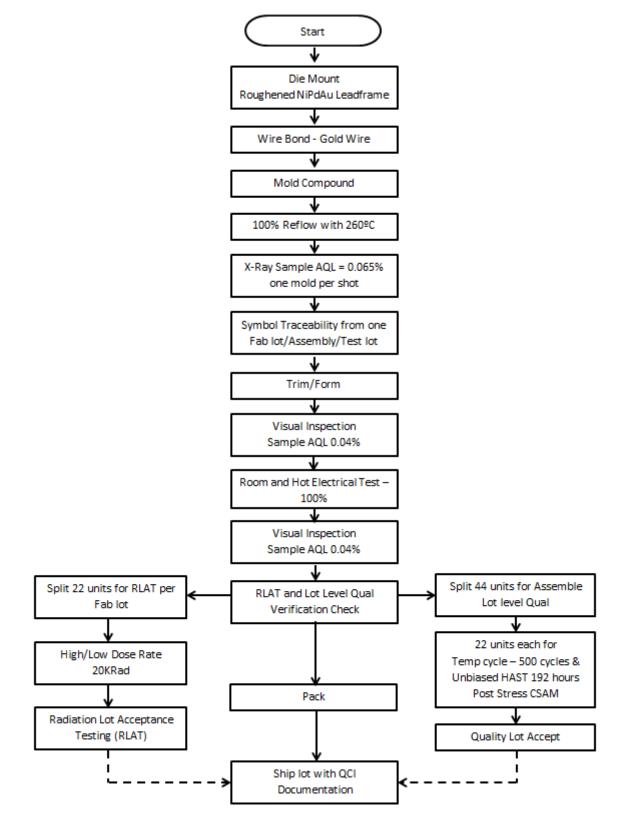
### 2.1 Device Introduction

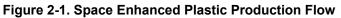
SN54SC245-SEP is a radiation hardened device in a plastic package which allows this device to be used in space applications. The device was verified immune to 43 MeV ×  $cm^2/mg$  at 125°C for single event latch-up (SEL). Each fabrication lot was tested according to MIL-STD-883 for Radiation Lot Acceptance Tested (RLAT) up to 30 krad (Si) and each assembly and test lot follows the process flow shown in Figure 2-1. To specify the quality of SN54SC245-SEP, the device is qualified with Space EP requirements. For further details, see Section 3.1.

3



### 2.2 SN54SC245-SEP Production Flow Chart







### **3 Device Qualification**

The following is the device qualification summary.

### 3.1 Qualification by Similarity (Qualification Family)

A new device can be qualified either by performing a full scale quality and reliability test on the actual device or using one or more previously qualified devices through *Qualification by Similarity* (QBS) rules. By establishing similarities between the new device and those qualified previously, repetitive tests were eliminated, allowing for a timely production release. Qualifying the differences between a previously qualified product and the new product under consideration was emphasized when adopting the QBS methodology.

The QBS rules for a technology, product, test parameter, or package defines which attributes are required to remain fixed for the QBS rules to apply. The expected attributes that were allowed to vary was reviewed, and a QBS plan was developed based on the previous reliability impact assessment, specifying what subset of the full complement of environmental stresses were required to evaluate the reliability impact of those variations. Each new device was reviewed for the conformance to the QBS rule sets applicable to the device. For more information, see JEDEC JESD47.

Note that qualification by similarity (qualification family) per JEDEC JESD47 is allowed					
Description	Condition	Sample Size Used/Rejects	Lots Required	Test Method	
Electromigration	Maximum recommended operating conditions	N/A	N/A	Per TI design rules	
Wire bond life	Maximum recommended operating conditions	N/A	N/A	Per TI design rules	
Electrical characterization	TI data sheet	30	1	N/A	
Electrostatic discharge sensitivity	НВМ	3 units/voltage	1	EIA/JESD22-A114	
	CDM	5 units/voltage	1	EIA/JESD22-C101	
Latch-up	Per technology	3/0	1	EIA/JESD78	
Physical dimensions	TI data sheet	5/0	1	EIA/JESD22- B100	
Thermal impedance	Theta-JA on board	Per Pin-Package	N/A	EIA/JESD51	
Bias life test	125°C / 1000 hours or equivalent	77/0	3	JESD22-A108 <sup>(1)</sup>	
Biased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A110 <sup>(1)</sup>	
Extended biased HAST	130°C / 85% / 250 hours (for reference)	77/0	1	JESD22-A110 <sup>(1)</sup>	
Unbiased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A110 <sup>(1)</sup>	
Temperature cycle	−65°C to +150°C non-biased for 500 cycles	77/0	3	JESD22-A104 <sup>(1)</sup>	
Solder heat	260°C for 10 seconds	22/0	1	JESD22-B106	
Resistance to solvents	Ink symbol only	12/0	1	JESD22-B107	
Solderability	Condition A (steam age for 8 hours)	22/0	1	ANSI/J-STD-002-92	
Flammability	Method A / Method B	5/0	1	UL-1964	
Bond shear	Per wire size	5 units × 30/0 bonds	3	JESD22-B116	
Bond pull strength	Per wire size	5 units × 30/0 bonds	3	ASTM F-459	
Die shear	Per die size	5/0	3	TM 2019	
High temperature storage	150°C / 1,000 hours	15/0	3	JESD22-A103-A <sup>(1)</sup>	
Moisture sensitivity	Surface mount only	12	1	J-STD-020-A <sup>(1)</sup>	
Radiation response characterization	Total ionization dose, and single- event latchup	5 units/dose level	1	MIL-STD-883/Method 1019	
Outgassing characterization	TML (Total mass lost), CVCM (collected volatile condensable material), WVR (water vapor recorded)	5	1	ASTM E595	

Table 3-1. Space Enhanced Products New Device Qualification Matrix

(1) Precondition performed per JEDEC Std. 22, Method A112/A113

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# 4 Outgas Test Report

Outgassing test was performed on 5 units. A total mass loss (TML) of 1.00% and collected volatile condensable material (CVCM) of 0.10% were used as screening levels for rejection of spacecraft materials. The outgas test was performed in a vacuum environment of less than  $5 \times 10$  –5 torr according to ASTM E 595, for a duration of 24 hours, at 125°C. The TML, CVCM, and the amount of Water Vapor Recovered (WVR) were measured after the test.

Table 4-1. Outgas Test Results							
SAMPLE	TML < 1.0%	CVCM < 0.1%					
SN54SC245MPWTSEP	PASS	PASS					

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